FAIRCHILD

SEMICONDUCTOR®

FDB8160_F085 N-Channel PowerTrench[®] MOSFET

30V, 80A, 1.8m Ω

Features

- Typ $r_{DS(on)}$ = 1.5m Ω at V_{GS} = 10V, I_D = 80A
- Typ Q_{g(10)} = 187nC at V_{GS} = 10V
- Low Miller Charge
- Low Qrr Body Diode
- UIS Capability (Single Pulse and Repetitive Pulse)
- Qualified to AEC Q101
- RoHS Compliant

Applications

- 12V Automotive Load Control
- Starter/Alternator Systems
- Electronic Power Steering Systems
- DC/DC converter





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October 2010

MOSFET Maximum Ratings $T_C = 25^{\circ}C$ unless otherwise noted

Symbol	Parameter	Ratings	Units
V _{DSS}	Drain to Source Voltage	30	V
V _{GS}	Gate to Source Voltage	±20	V
	Drain Current Continuous (T _C < 160°C, V _{GS} = 10V)	80	А
D	Pulsed	See Figure 4	A
E _{AS}	Single Pulse Avalanche Energy (Note	1) 1290	mJ
C	Power Dissipation	254	W
P _D	Derate above 25°C	1.7	W/ºC
T _J , T _{STG}	Operating and Storage Temperature	-55 to +175	°C

Thermal Characteristics

R_{\thetaJC}	Maximum Thermal Resistance Junction to Case	0.59	°C/W
$R_{ hetaJA}$	Maximum Thermal Resistance Junction to Ambient TO-263,1in ² copper pad area	43	°C/W

Package Marking and Ordering Information

Device Marking	Device	Package	Reel Size	Tape Width	Quantity
FDB8160	FDB8160_F085	TO-263AB	330mm	24mm	800 units

Electrical Characteristics T_J = 25°C unless otherwise noted

Symbol	Parameter	Test Conditions	Min	Тур	Max	Units	
Off Characteristics							
D	Drain to Course Drackdown Valtage	1 - 050 + 1/(-0)/(-0)/(-0)/(-0)/(-0)/(-0)/(-0)/(-0)	20				
B _{VDSS}	Drain to Source Breakdown Voltage	I _D = 250μA, V _{GS} = 0V	30	-	-	V	
Inco	Zero Gate Voltage Drain Current	$V_{DS} = 24V, V_{GS} = 0V$	-	-	1	uА	
DSS	Loro Gato Voltago Brain Ganone	$T = 150^{\circ}C$	_		250	μι	

T_J = 150°C

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On	Characteristics

I_{GSS}

Gate to Source Leakage Current

V _{GS(th)}	Gate to Source Threshold Voltage	$V_{GS} = V_{DS}, I_D = 250 \mu A$	2	2.9	4	V
r	Drain to Source On Resistance	I _D = 80A, V _{GS} = 10V	-	1.5	1.8	mΩ
DS(on)		I _D = 80A, V _{GS} = 10V, T _J = 175°C	-	2.6	3.1	mΩ

 $V_{GS} = \pm 20V$

Dynamic Characteristics

C _{iss}	Input Capacitance				11825	-	pF
C _{oss}	Output Capacitance	V _{DS} = 15V, V _{GS} = 0V, f = 1MHz		-	1810	-	pF
C _{rss}	Reverse Transfer Capacitance			-	1240	-	pF
Rg	Gate Resistance	f = 1MHz		-	1.75	-	Ω
Q _{g(TOT)}	Total Gate Charge at 10V	V _{GS} = 0 to 10V		-	187	243	nC
Q _{g(th)}	Threshold Gate Charge	V_{GS} = 0 to 2V	V _{DD} = 15V	-	20	26	nC
Q _{gs}	Gate to Source Gate Charge		I _D = 80A		43	-	nC
Q _{gs2}	Gate Charge Threshold to Plateau				23	-	nC
Q _{gd}	Gate to Drain "Miller" Charge			-	57	-	nC

250

±100

nA

Symbol	Parameter	Test Conditions	Min	Тур	Max	Units
Switch	ning Characteristics					
t _{on}	Turn-On Time		-	-	60	ns
t _{d(on)}	Turn-On Delay Time		-	17.2	-	ns
t _r	Turn-On Rise Time	V _{DD} = 15V, I _D = 80A,	-	18.9	-	ns
t _{d(off)}	Turn-Off Delay Time	V _{GS} = 10V, R _{GS} = 1.3Ω	-	60	-	ns
t _f	Turn-Off Fall Time		-	27	-	ns
t _{off}	Turn-Off Time		-	-	137	ns
'n	Reverse Recovery Time		-	0.8 48	1.0 62	v ns
V _{SD}	Source to Drain Diode Voltage	I _{SD} = 40A	-	0.8	1.0	V
Q _{rr}	Reverse Recovery Charge	—— I _F = 80A, dI _{SD} /dt = 100A/μs	-	42	55	nC
lotes:	₁ = 25°C, L = 0.63mH, I _{AS} = 64A			<u> </u>		

This product has been designed to meet the extreme test conditions and environment demanded by the automotive industry. For a copy of the requirements, see AEC Q101 at: http://www.aecouncil.com/ All Fairchild Semiconductor products are manufactured, assembled and tested under ISO9000 and QS9000 quality systems certification.



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